



2N6282 – 2N6283 – 2N6284

NPN SILICON DARLINGTON POWER TRANSISTOR

The 2N6282, 2N6283 and 2N6284 are mounted in TO-3 metal package. They are designed for use in general-purpose amplifier and low-frequency switching applications.

The complementary PNP are 2N6285, 2N6286, 2N6287
Compliance to RoHS.

ABSOLUTE MAXIMUM RATINGS

Symbol	Ratings		Value	Unit
V_{CEO}	Collector-Emitter Voltage ($I_B=0$)	2N6282	60	V
		2N6283	80	
		2N6284	100	
V_{CBO}	Collector-Base Voltage ($I_E=0$)	2N6282	60	V
		2N6283	80	
		2N6284	100	
V_{EBO}	Emitter-Base Voltage ($I_C=0$)	2N6282	5	V
		2N6283		
		2N6284		
I_C	Collector Current	2N6282	20	A
		2N6283		
		2N6284		
I_{CM}	Collector Peak Current	2N6282	40	A
		2N6283		
		2N6284		
I_B	Base Current	2N6282	0.5	A
		2N6283		
		2N6284		
P_T	Power Dissipation	@ $T_C = 25^\circ$	160	W/°C
		2N6282		
		2N6283		
T_J	Junction Temperature	2N6282	200	°C
		2N6283		
		2N6284		
T_S	Storage Temperature	2N6282	-65 to +200	°C
		2N6283		
		2N6284		

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THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit
R_{thJ-C}	Thermal Resistance Junction-Case	1.09	°C/W

ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings	Test Condition(s)		Min	Typ	Max	Unit
$V_{\text{CEO(SUS)}}$	Collector-Emitter Breakdown Voltage (*)	$I_{\text{C}}= 200 \text{ m A}$ $I_{\text{B}}= 0$	2N6282	60	-	-	V
			2N6283	80	-	-	
			2N6284	100	-	-	
I_{CEO}	Collector Cutoff Current	$V_{\text{CE}}= 30 \text{ V}, I_{\text{B}}= 0$	2N6282	-	-	1	mA
		$V_{\text{CE}}= 40 \text{ V}, I_{\text{B}}= 0$	2N6283				
		$V_{\text{CE}}= 50 \text{ V}, I_{\text{B}}= 0$	2N6284				
I_{EBO}	Emitter Cutoff Current	$V_{\text{BE}}= 5 \text{ V}, I_{\text{C}}= 0$	2N6282	-	-	2	mA
			2N6283				
			2N6284				
I_{CEX}	Collector Cutoff Current	$V_{\text{CE}}= 60 \text{ V}, V_{\text{BE}}= -1.5 \text{ V}$	2N6282	-	-	500	μA
		$V_{\text{CE}}= 80 \text{ V}, V_{\text{BE}}= -1.5 \text{ V}$	2N6283				
		$V_{\text{CE}}= 100 \text{ V}, V_{\text{BE}}= -1.5 \text{ V}$	2N6284				
		$V_{\text{CE}}= 60 \text{ V}, V_{\text{BE}}= -1.5 \text{ V}$ $T_{\text{C}}= 150^{\circ}\text{C}$	2N6282	-	-	5	mA
		$V_{\text{CE}}= 80 \text{ V}, V_{\text{BE}}= -1.5 \text{ V}$ $T_{\text{C}}= 150^{\circ}\text{C}$	2N6283				
		$V_{\text{CE}}= 100 \text{ V}, V_{\text{BE}}= -1.5 \text{ V}$ $T_{\text{C}}= 150^{\circ}\text{C}$	2N6284				
$V_{\text{CE(SAT)}}$	Collector-Emitter saturation Voltage (*)	$I_{\text{C}}= 10 \text{ A}, I_{\text{B}}= 40 \text{ mA}$	2N6282	-	-	2	V
			2N6283				
			2N6284				
$V_{\text{CE(SAT)}}$	Collector-Emitter saturation Voltage (*)	$I_{\text{C}}= 20 \text{ A}, I_{\text{B}}= 200 \text{ mA}$	2N6282	-	-	3	V
			2N6283				
			2N6284				
$V_{\text{BE(SAT)}}$	Base-Emitter saturation Voltage (*)	$I_{\text{C}}= 20 \text{ A}, I_{\text{B}}= 200 \text{ mA}$	2N6282	-	-	4	V
			2N6283				
			2N6284				
V_{BE}	Base-Emitter Voltage (*)	$V_{\text{CE}}= 3 \text{ V}, I_{\text{C}}= 10 \text{ A}$	2N6282	-	-	2,8	V
			2N6283				
			2N6284				

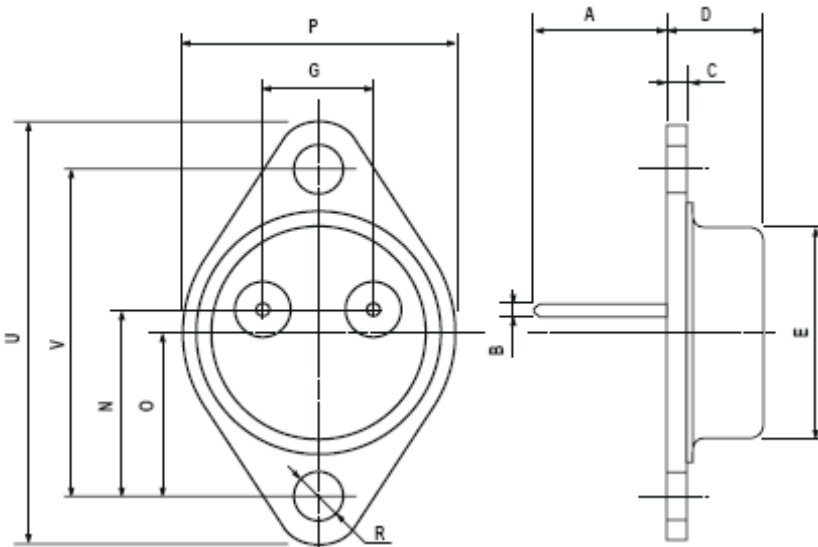
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Symbol	Ratings	Test Condition(s)		Min	Typ	Max	Unit
h_{FE}	DC Current Gain (*)	$V_{CE}= 3\text{ V}, I_C= 10\text{ A}$	2N6282	750	-	18000	-
			2N6283				
			2N6284				
		$V_{CE}= 3\text{ V}, I_C= 20\text{ A}$	2N6282	100	-	-	
			2N6283				
			2N6284				
C_{OB}	Output Capacitance	$I_E= 0\text{ A}, V_{CB}= 10\text{V}$ $f= 1\text{MHz}$	2N6282	-	-	400	pF
			2N6283				
			2N6284				

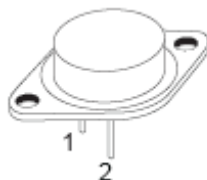
(*) Pulse Width $\approx 300\text{ }\mu\text{s}$, Duty Cycle $\angle 2.0\%$

MECHANICAL DATA CASE TO-3

DIMENSIONS (mm)		
	min	max
A	11	13.10
B	0.97	1.15
C	1.5	1.65
D	8.32	8.92
F	19	20
G	10.70	11.1
N	16.50	17.20
P	25	26
R	4	4.09
U	38.50	39.30
V	30	30.30



Pin 1 :	Base
Pin 2 :	Emitter
Case :	Collector



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